

International
IOR Rectifier

SD600N/R SERIES

STANDARD RECOVERY DIODES

Stud Version

Features

- Wide current range
- High voltage ratings up to 3200V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

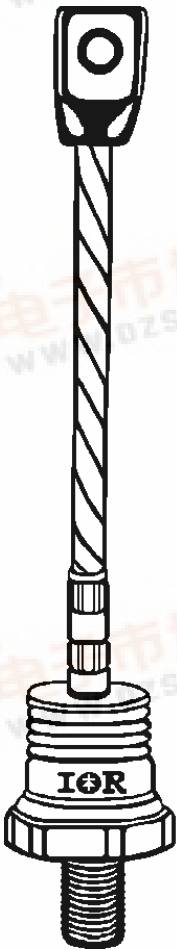
600A

Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	SD600N/R		Units
	04 to 20	25 to 32	
$I_{F(AV)}$	600	600	A
@ T_c	92	54	°C
$I_{F(RMS)}$	940	940	A
I_{FSM} @ 50Hz	13000	10500	A
@ 60Hz	13600	11000	A
I^2t @ 50Hz	845	551	K A ² s
@ 60Hz	772	503	K A ² s
V_{RRM} range	400 to 2000	2500 to 3200	V
T_j	- 40 to 180	- 40 to 150	°C



case style
B-8



SD600N/R Series

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. m A
SD600N/R	04	400	500	35
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	
	28	2800	2900	
	32	3200	3300	

Forward Conduction

Parameter		SD600N/R		Units	Conditions			
		04 to 20	25 to 32					
$I_{F(AV)}$	Max. average forward current @ Case temperature	600	600	A	180° conduction, half sine wave			
		92	54	°C				
$I_{F(AV)}$	Max. average forward current @ Case temperature	570	375	A	180° conduction, half sine wave			
		100	100	°C				
$I_{F(RMS)}$	Max. RMS forward current	940	940	A	DC @ $T_C = 75^{\circ}\text{C}$ (04 to 20), $T_C = 36^{\circ}\text{C}$ (25 to 32)			
I_{FSM}	Max. peak, one-cycle forward, non-repetitive surge current	13000	10500	A	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J$ max.	
		13600	11000		t = 8.3ms	reapplied		
		10900	8830		t = 10ms	100% V_{RRM}		
		11450	9250		t = 8.3ms	reapplied		
I^2t	Maximum I^2t for fusing	845	551	KA ² s	t = 10ms	No voltage		
		772	503		t = 8.3ms	reapplied		
		598	390		t = 10ms	100% V_{RRM}		
		546	356		t = 8.3ms	reapplied		
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	8450	5510	KA ² √s	t = 0.1 to 10ms, no voltage reapplied			
$V_{F(TO)1}$	Low level value of threshold voltage	0.78	0.84	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ max.			
$V_{F(TO)2}$	High level value of threshold voltage	0.87	0.88		$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ max.			
r_{f1}	Low level value of forward slope resistance	0.35	0.40	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ max.			
r_{f2}	High level value of forward slope resistance	0.31	0.38		$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ max.			
V_{FM}	Max. forward voltage drop	1.31	1.44	V	$I_{pk} = 1500\text{A}$, $T_J = T_J$ max, $t_p = 10\text{ms}$ sinusoidal wave			

Thermal and Mechanical Specifications

Parameter		SD600N/R		Units	Conditions
		04 to 20	25 to 32		
T _J	Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T _{stg}	Max. storage temperature range	-55 to 200	-55 to 200		
R _{thJC}	Max. thermal resistance, junction to case	0.1		K/W	DC operation
R _{thCS}	Max. thermal resistance, case to heatsink	0.04			Mounting surface, smooth, flat and greased
T	Max. allowed mounting torque ±10%	50		Nm	Not lubricated threads
wt	Approximate weight	454		g	
Case style		B - 8			See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	T _J = T _J max.
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

Ordering Information Table

Device Code

SD60N32PSC

1

2

3

4

5

6

7

8

1

-

Diode

2

-

Essential part number

3

-

0 = Standard recovery

4

-

N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)

5

-

Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)

6

-

P = Stud base B-8 3/4" 16UNF-2A
M = Stud base B-8 M24 X 1.5

7

-

S = Isolated lead with silicone sleeve
(Red = Reverse Polarity; Blue = Normal Polarity)
T = Threaded Top Terminal 3/8" 24UNF-2A
None = Non isolated lead

8

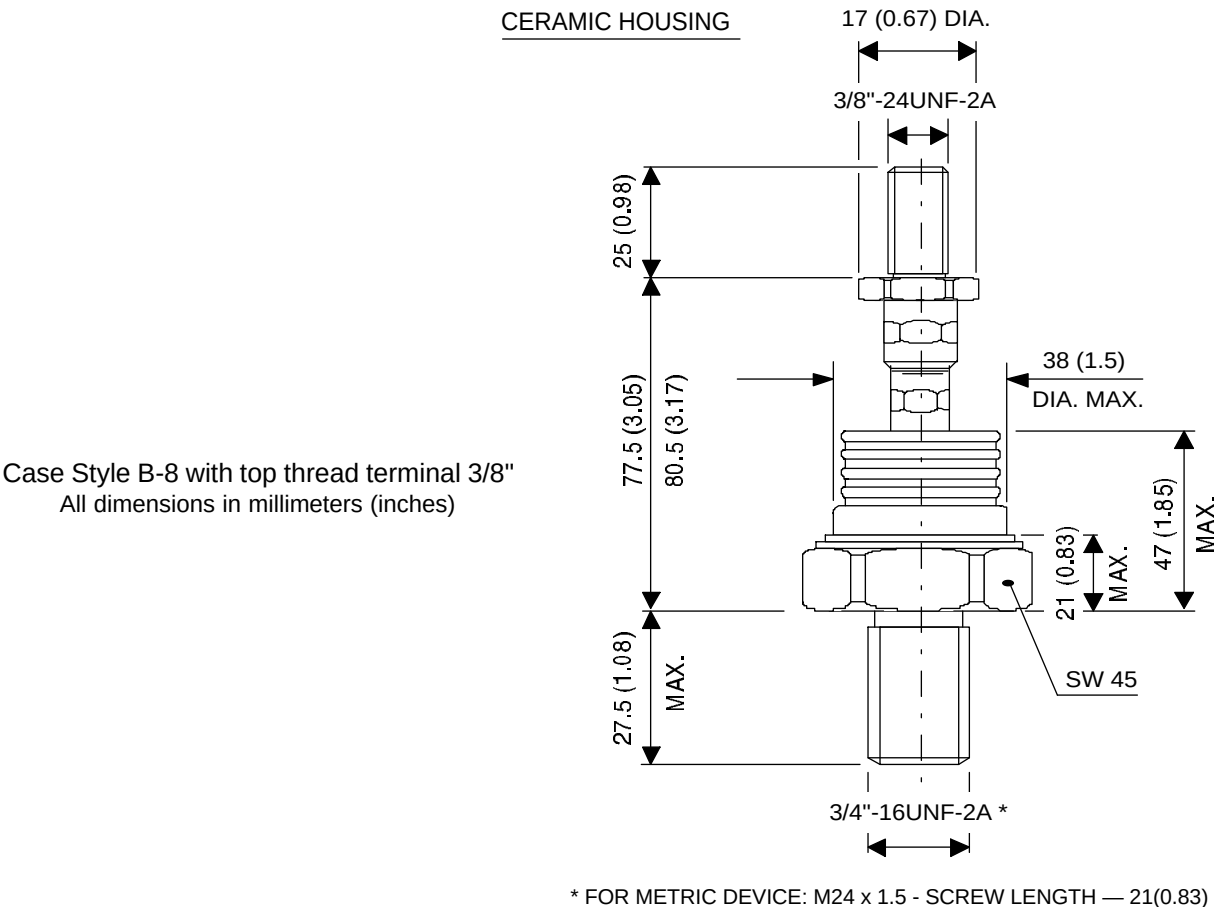
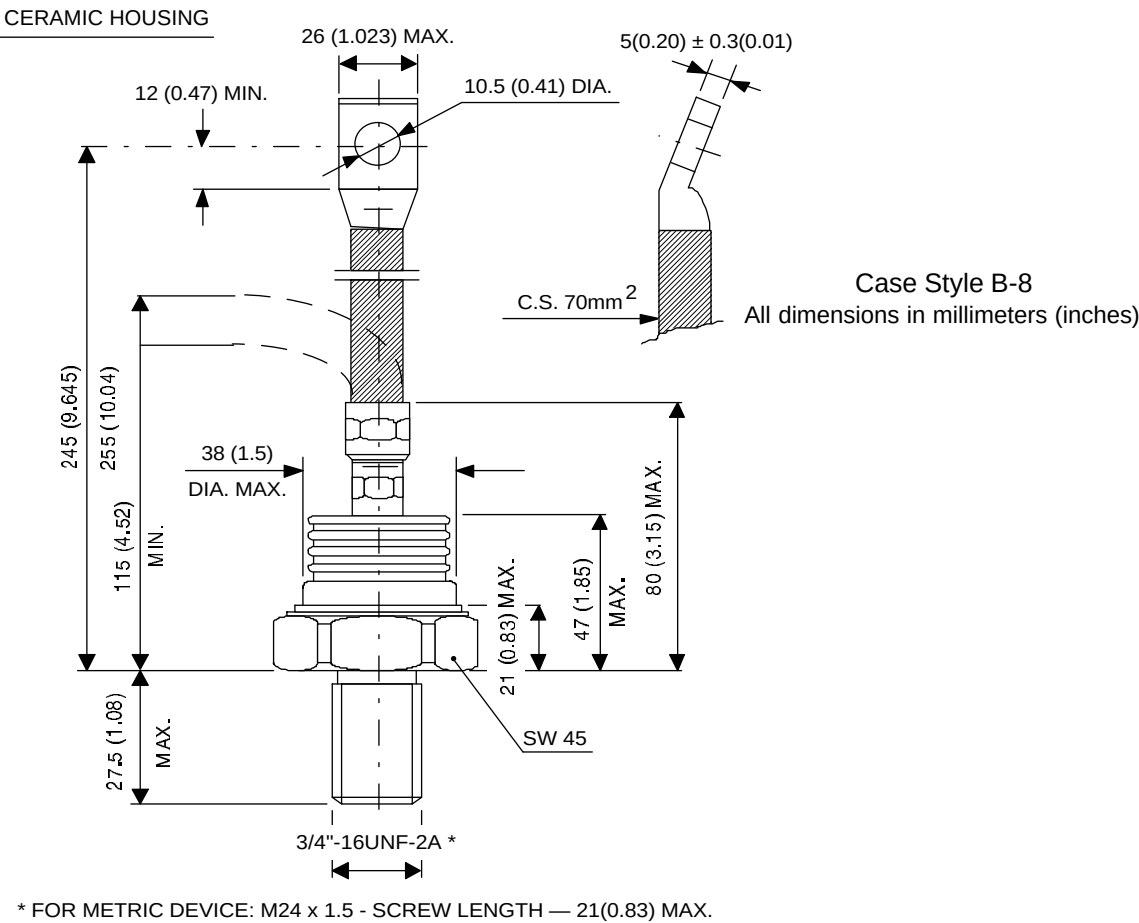
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C = Ceramic Housing

NOTE: Available for rotating applications (Contact factory)

SD600N/R Series

Outlines Table



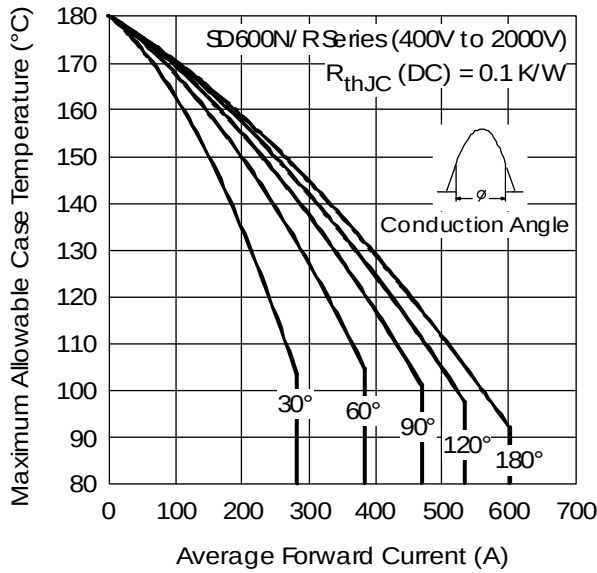


Fig. 1 - Current Ratings Characteristics

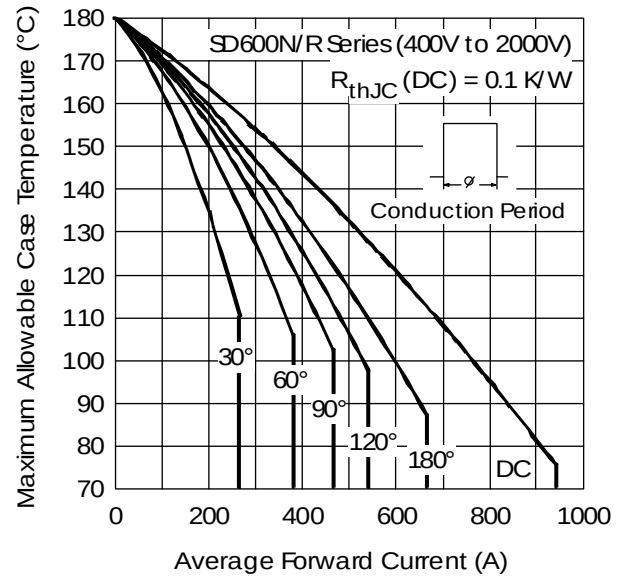


Fig. 2 - Current Ratings Characteristics

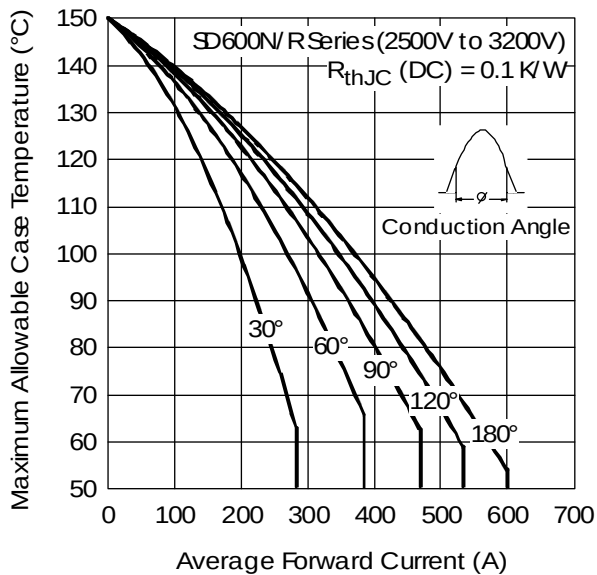


Fig. 3 - Current Ratings Characteristics

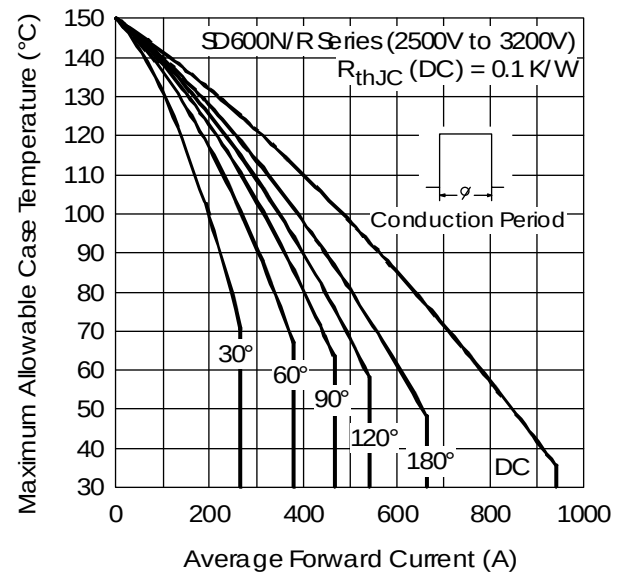
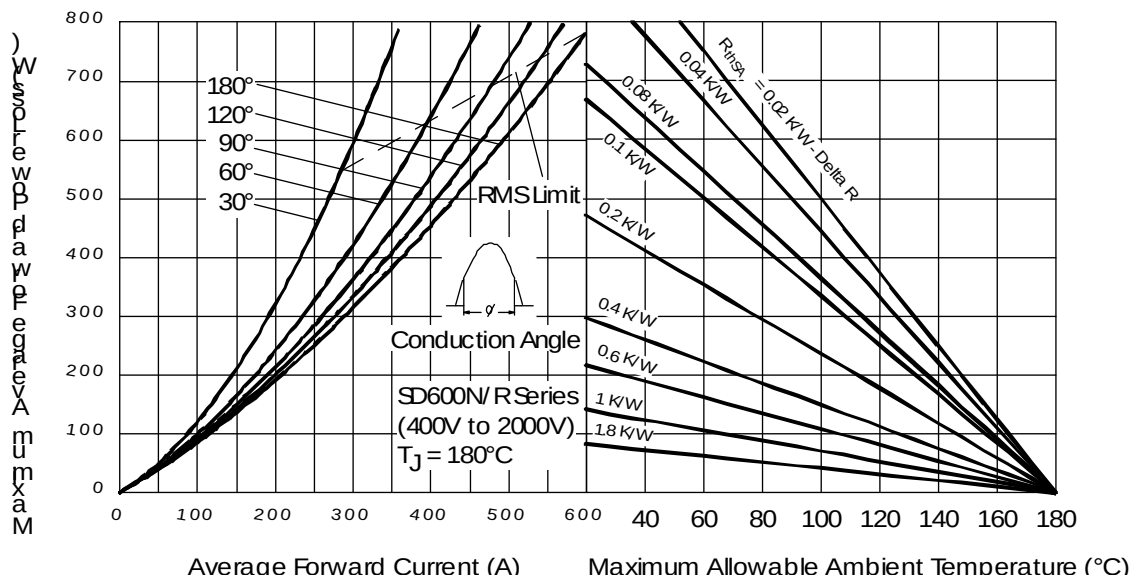


Fig. 4 - Current Ratings Characteristics



SD600N/R Series

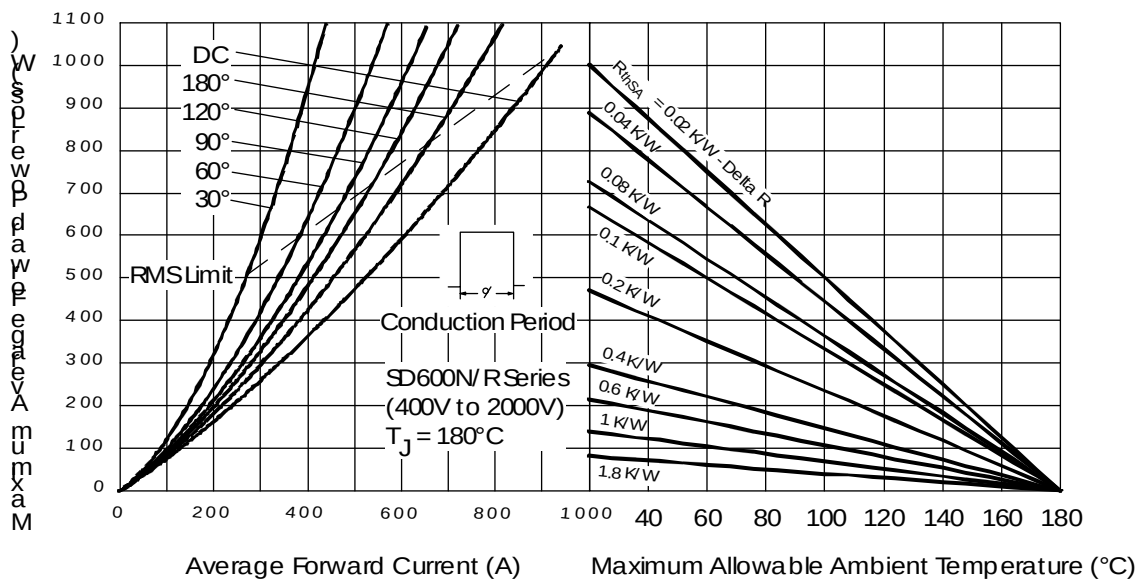


Fig. 6 - Forward Power Loss Characteristics

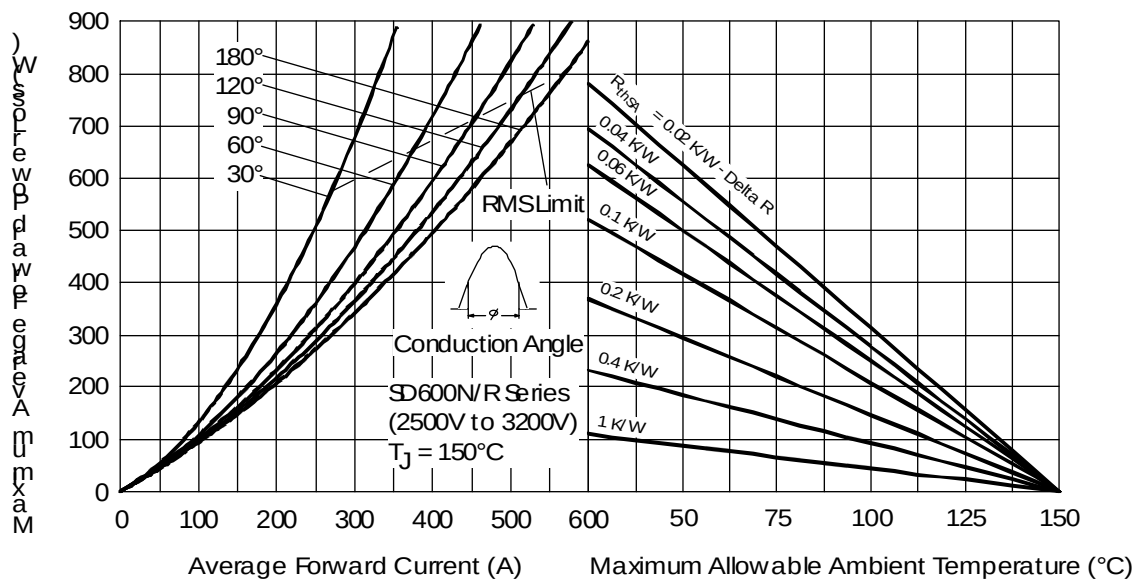


Fig. 7 - Forward Power Loss Characteristics

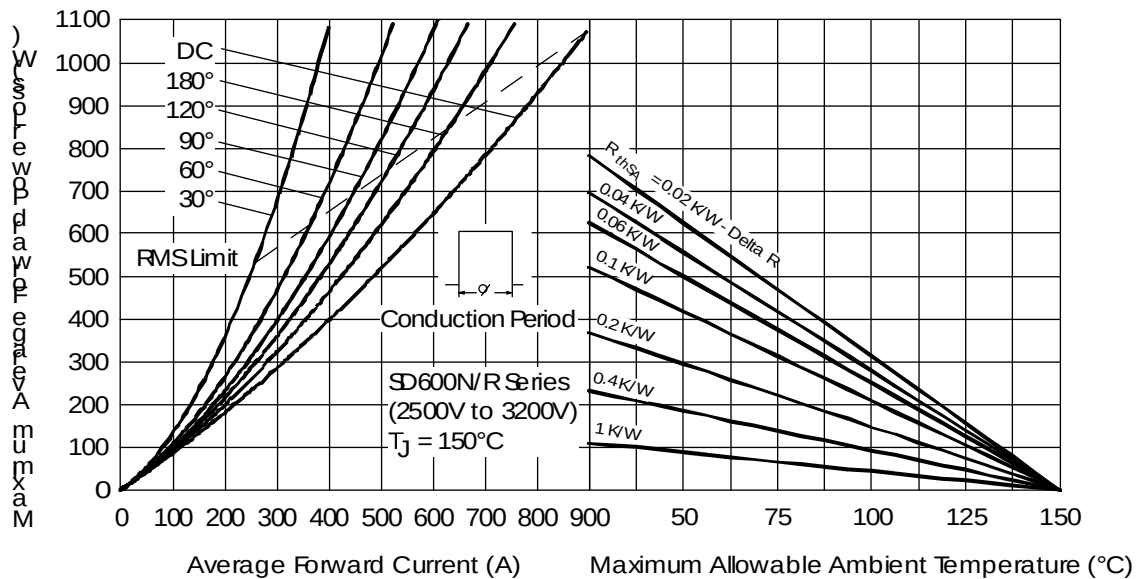


Fig. 8 - Forward Power Loss Characteristics

SD600N/R Series

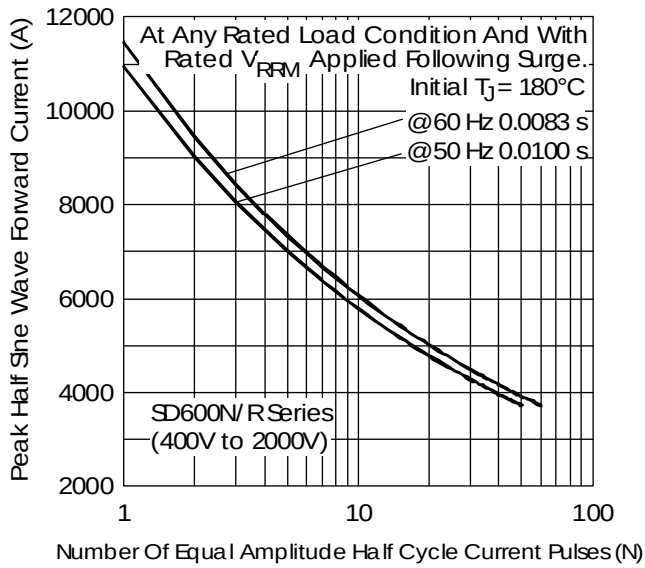


Fig. 9 - Maximum Non-Repetitive Surge Current

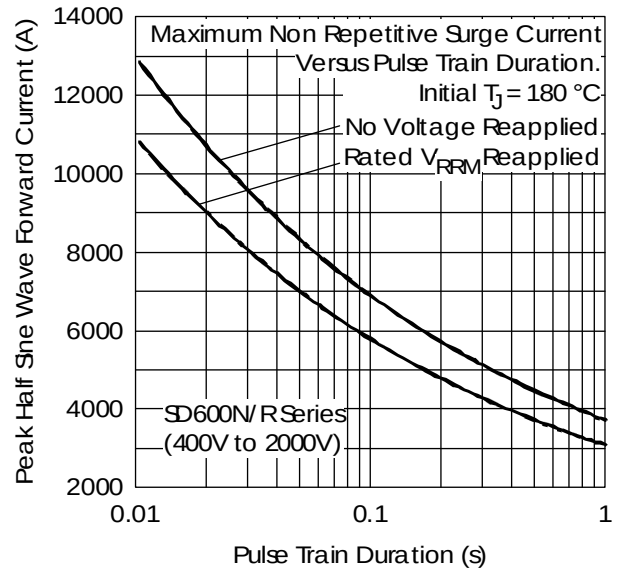


Fig. 10 - Maximum Non-Repetitive Surge Current

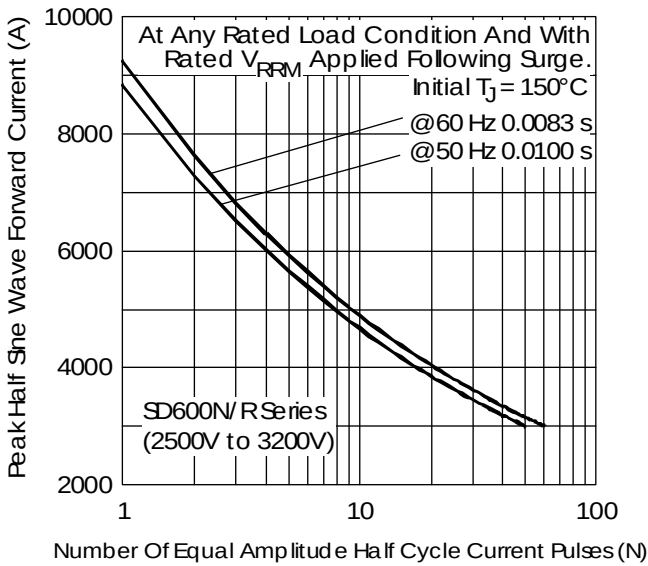


Fig. 11 - Maximum Non-Repetitive Surge Current

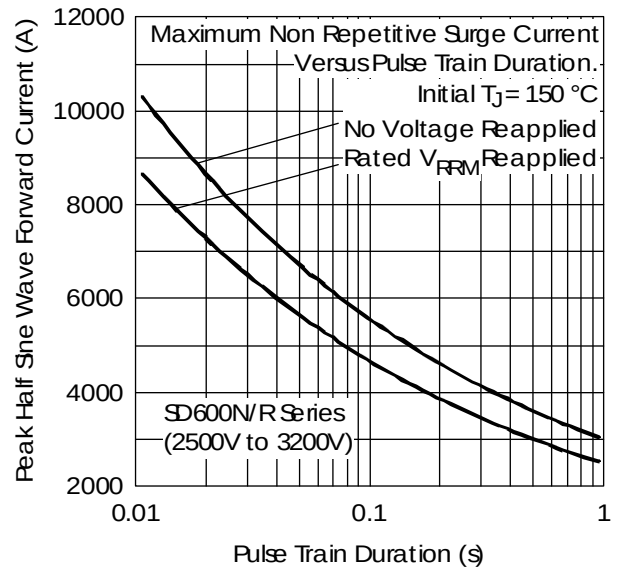


Fig. 12 - Maximum Non-Repetitive Surge Current

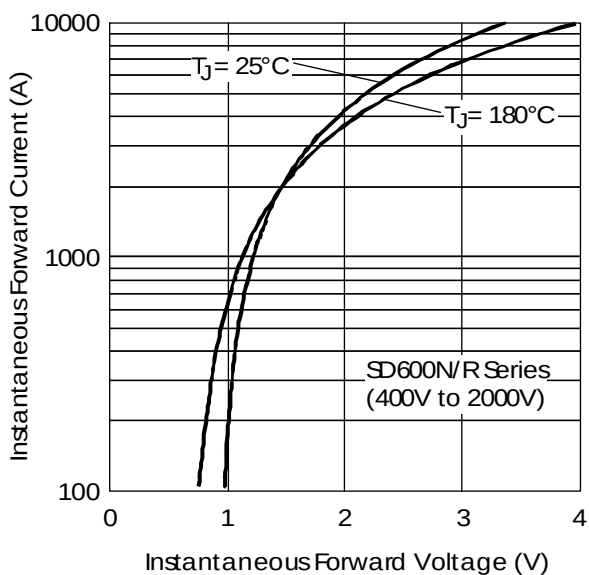


Fig. 13 - Forward Voltage Drop Characteristics

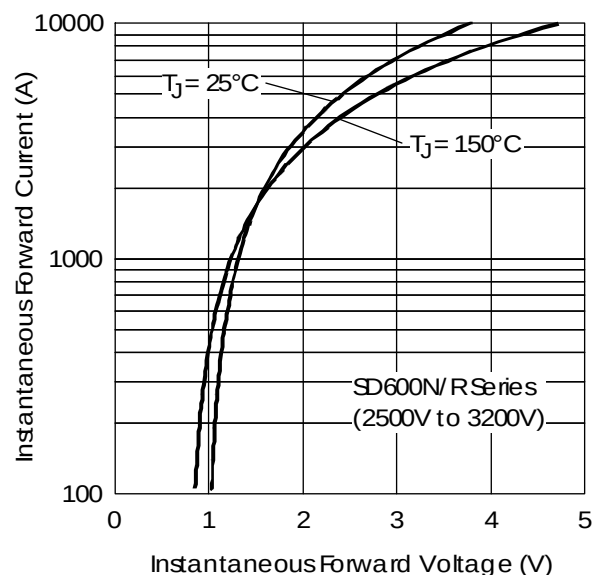


Fig. 14 - Forward Voltage Drop Characteristics

SD600N/R Series

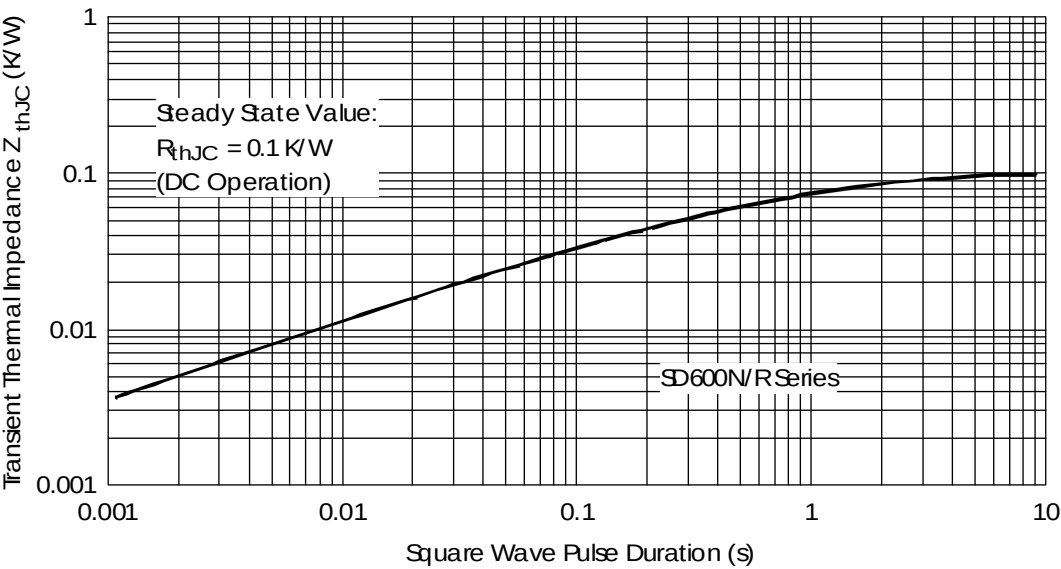


Fig. 15 - Thermal Impedance Z_{thJC} Characteristics